CEL

NPN SILICON RF TWIN TRANSISTOR

μPA828TD

NPN SILICON RF TRANSISTOR (WITH 2 ELEMENTS) IN A 6-PIN LEAD-LESS MINIMOLD (M16, 1208 PKG)

FEATURES

- Built-in low phase distortion transistor suited for OSC applications
  f_T = 9.0 GHz TYP., $|S_{21e}|^2$ = 7.5 dB TYP. @ V_{CE} = 1 V, I_C = 10 mA, f = 2 GHz
  NF = 1.3 dB TYP. @ V_{CE} = 1 V, I_C = 3 mA, f = 2 GHz
- Built-in 2 transistors (2 × NE687)
- 6-pin lead-less minimold (M16, 1208 PKG)

BUILT-IN TRANSISTORS

	Q1, Q2
3-pin thin-type ultra super minimold part No.	NE687

<R> ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
μPA828TD	μPA828TD-A	6-pin lead-less minimold (M16, 1208 PKG) (Pb-Free)	50 pcs (Non reel)	• 8 mm wide embossed taping
μPA828TD-T3	μPA828TD-T3-A		10 kpcs/reel	• Pin 1 (Q1 Collector), Pin 6 (Q1 Base) face the perforation side of the tape

Remark To order evaluation samples, contact your nearby sales office.
The unit sample quantity is 50 pcs.

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V_{CBO}	5.0	V
Collector to Emitter Voltage	V_{CEO}	3.0	V
Emitter to Base Voltage	V_{EBO}	2	V
Collector Current	I_C	30	mA
Total Power Dissipation	P_{tot} Note	90 in 1 element	mW
		180 in 2 elements	
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	−65 to +150	°C

Note Mounted on 1.08 cm^2 × 1.0 mm (t) glass epoxy PCB

ELECTRICAL CHARACTERISTICS (T_A = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characterstics						
Collector Cut-off Current	I_{CBO}	V_{CB} = 5 V, I_E = 0 mA	–	–	100	nA
Emitter Cut-off Current	I_{EBO}	V_{EB} = 1 V, I_C = 0 mA	–	–	100	nA
DC Current Gain	h_{FE} Note 1	V_{CE} = 2 V, I_C = 20 mA	70	–	140	–
RF Characterstics						
Gain Bandwidth Product (1)	f_T	V_{CE} = 1 V, I_C = 10 mA, f = 2 GHz	7.0	9.0	–	GHz
Gain Bandwidth Product (2)	f_T	V_{CE} = 2 V, I_C = 20 mA, f = 2 GHz	9.0	11.0	–	GHz
Insertion Power Gain (1)	$\|S_{21e}\|^2$	V_{CE} = 1 V, I_C = 10 mA, f = 2 GHz	6.0	7.5	–	dB
Insertion Power Gain (2)	$\|S_{21e}\|^2$	V_{CE} = 2 V, I_C = 20 mA, f = 2 GHz	7.0	8.5	–	dB
Noise Figure (1)	NF	V_{CE} = 1 V, I_C = 3 mA, f = 2 GHz, $Z_S = Z_{opt}$	–	1.3	2.0	dB
Noise Figure (2)	NF	V_{CE} = 2 V, I_C = 3 mA, f = 2 GHz, $Z_S = Z_{opt}$	–	1.3	2.0	dB
Reverse Transfer Capacitance	C_{re} Note 2	V_{CB} = 2 V, I_E = 0 mA, f = 1 MHz	–	0.4	0.8	pF
h_{FE} Ratio	h_{FE1}/h_{FE2}	V_{CE} = 2 V, I_C = 20 mA, h_{FE1} : Smaller value of Q1 and Q2, h_{FE2} : Larger value of Q1 and Q2	0.85	–	–	–

Notes 1. Pulse measurement: PW ≤ 350 μs, Duty Cycle ≤ 2%

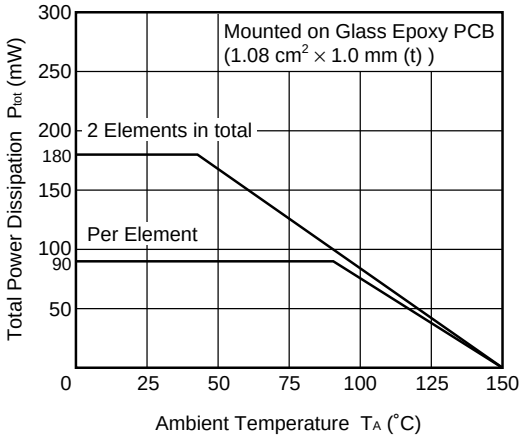
2. Collector to base capacitance when the emitter grounded.

h_{FE} CLASSIFICATION

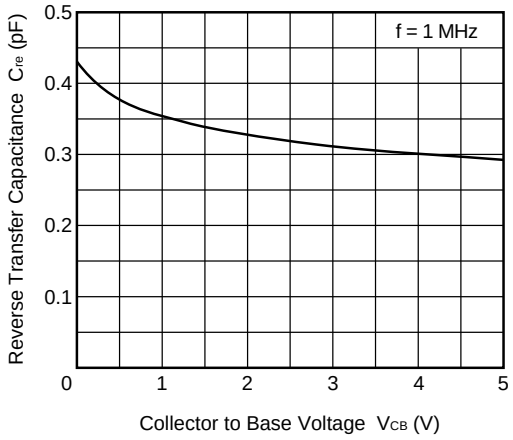
Rank	FB
Marking	kL
h_{FE} Value	70 to 140

<R> **TYPICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)**

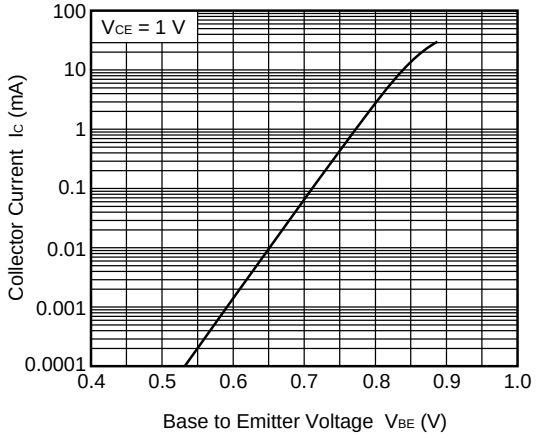
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



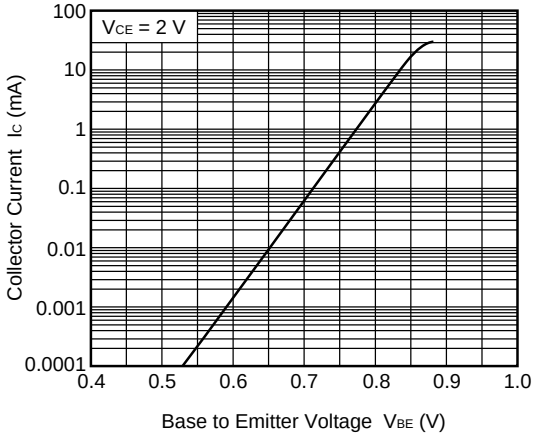
REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



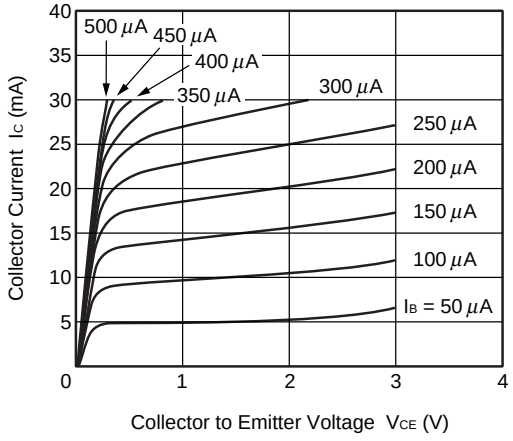
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

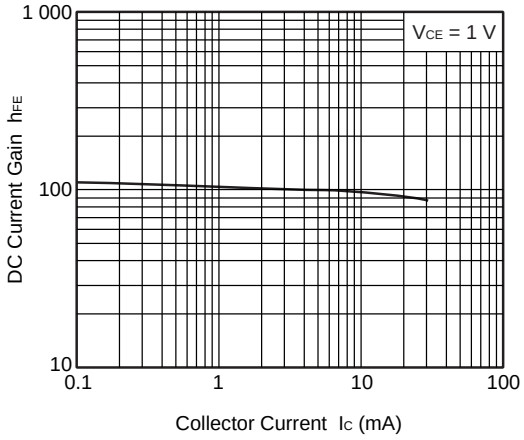


COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

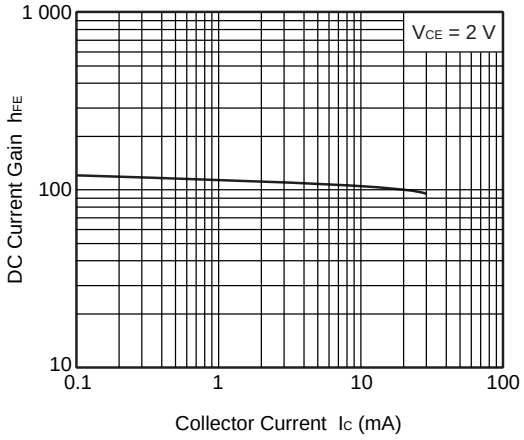


Remark The graphs indicate nominal characteristics.

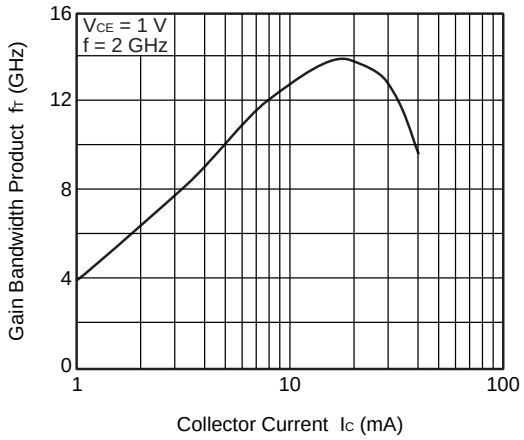
DC CURRENT GAIN vs.
COLLECTOR CURRENT



DC CURRENT GAIN vs.
COLLECTOR CURRENT



GAIN BANDWIDTH PRODUCT
vs. COLLECTOR CURRENT



GAIN BANDWIDTH PRODUCT
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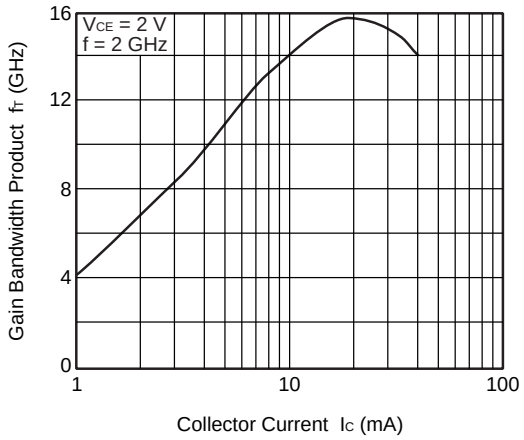
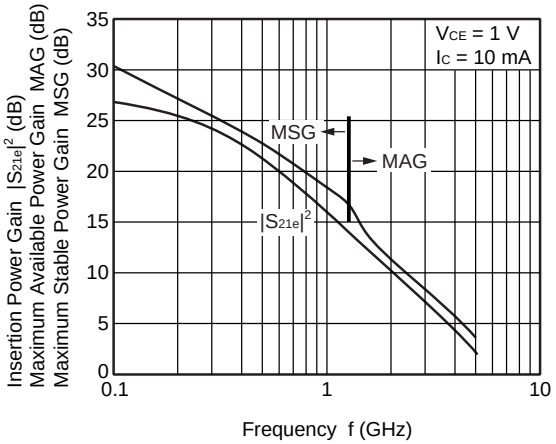
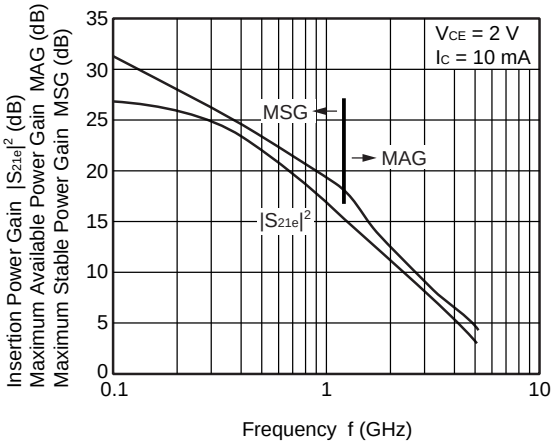


INSERTION POWER GAIN,
MAG, MSG vs. FREQUENCY



INSERTION POWER GAIN,
MAG, MSG vs. FREQUENCY



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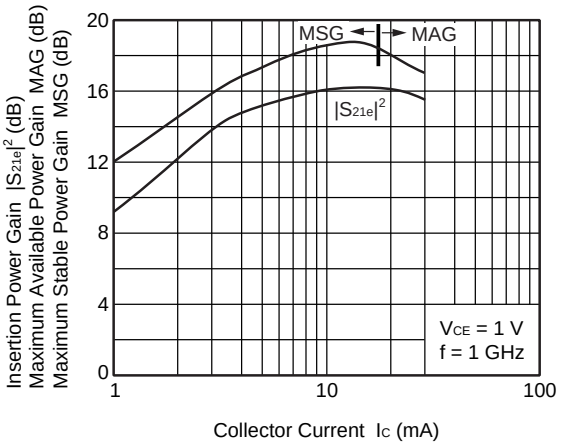
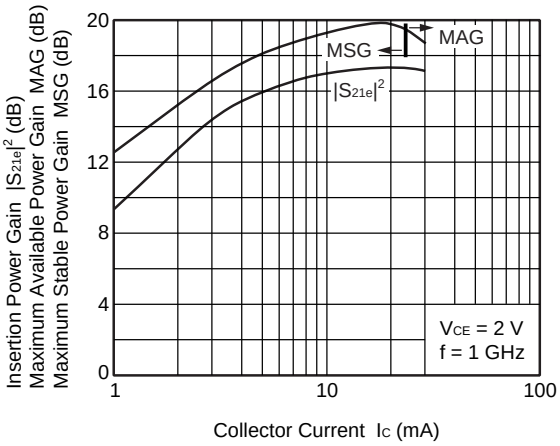
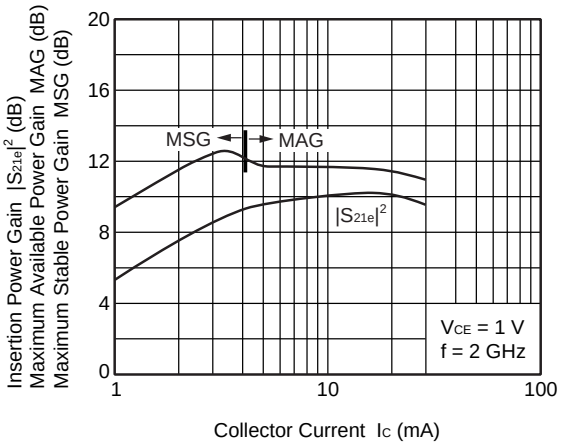
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



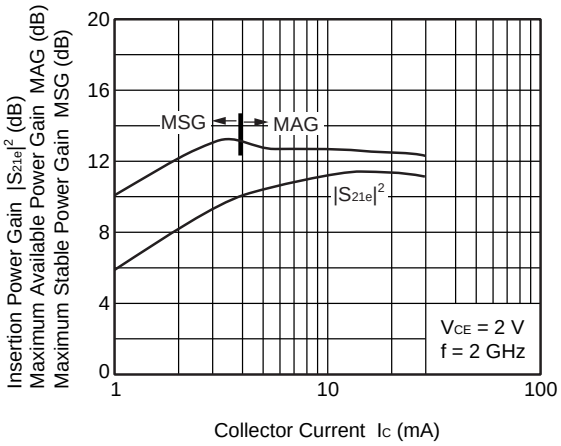
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



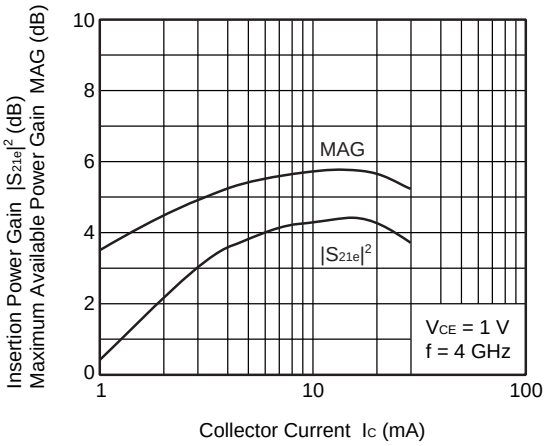
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



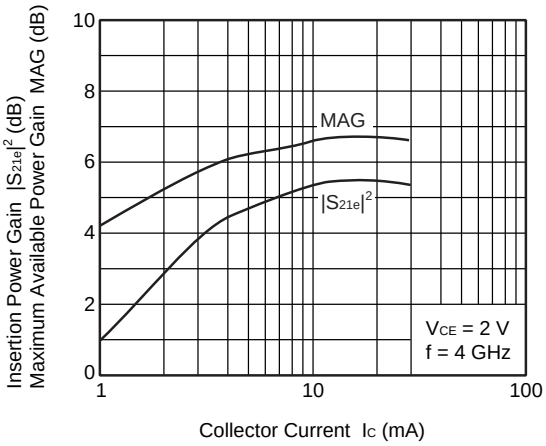
INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT



INSERTION POWER GAIN, MAG vs. COLLECTOR CURRENT



INSERTION POWER GAIN, MAG vs. COLLECTOR CURRENT



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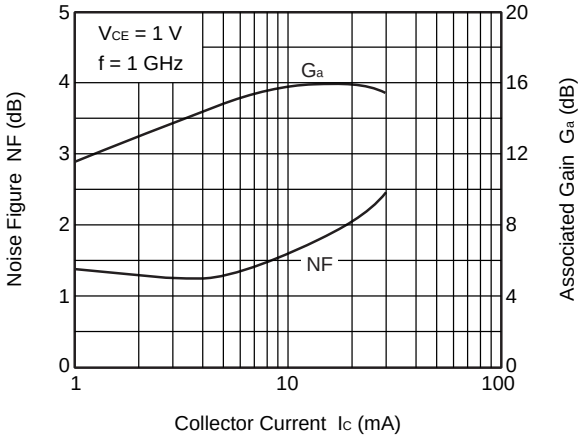
NOISE FIGURE, ASSOCIATED GAIN vs. COLLECTOR CURRENT



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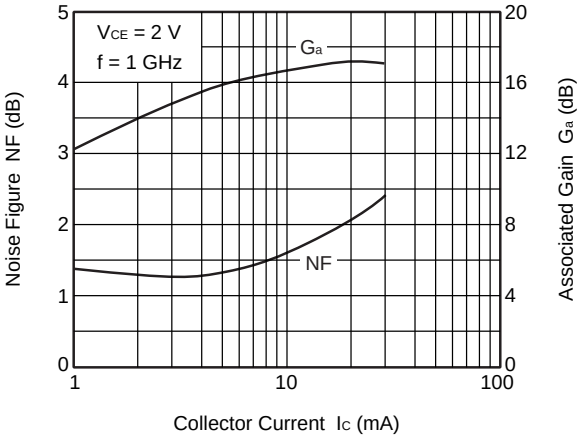

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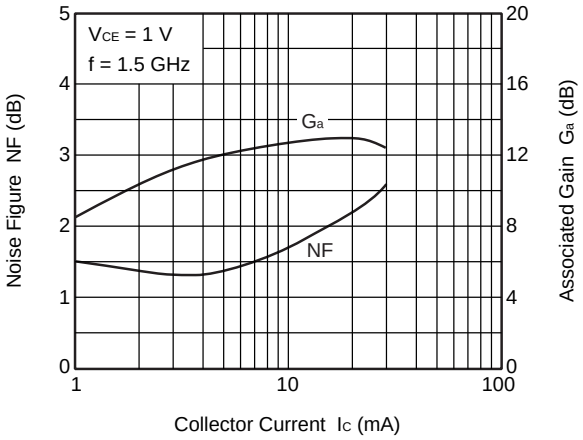

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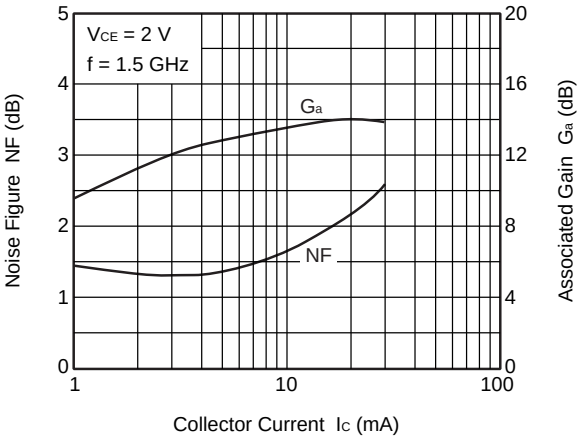

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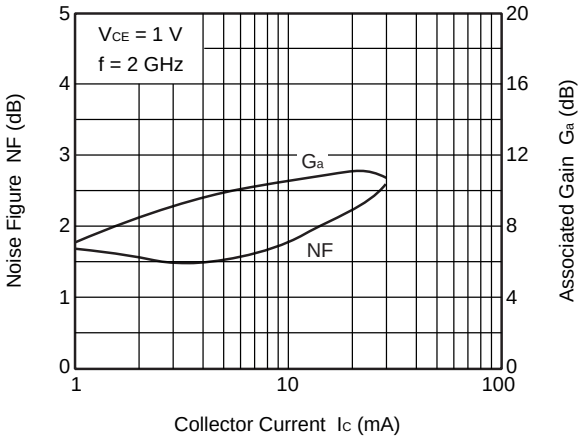

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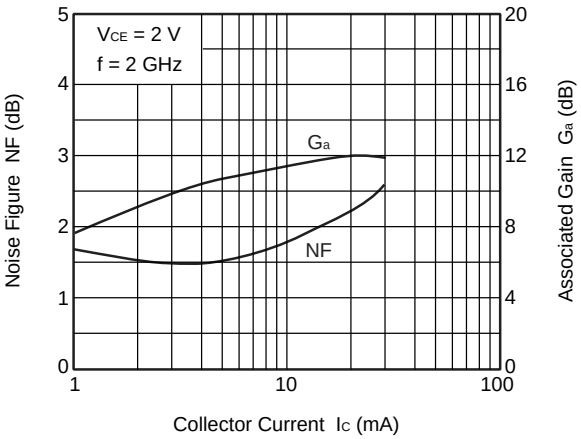

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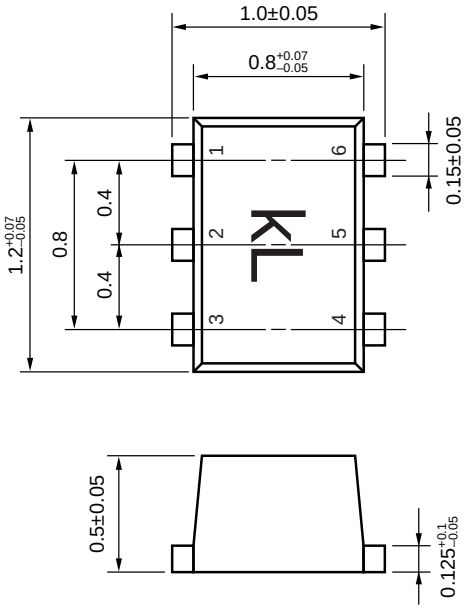
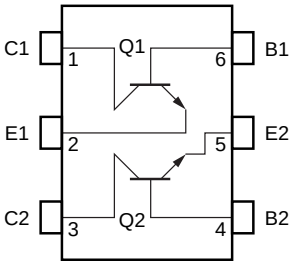
PACKAGE DIMENSIONS

6-PIN LEAD-LESS MINIMOLD (M16, 1208 PKG) (UNIT: mm)



(Top View)



PIN CONNECTIONS

1. Collector (Q1)
2. Emitter (Q1)
3. Collector (Q2)
4. Base (Q2)
5. Emitter (Q2)
6. Base (Q1)

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